

30 V, N-channel Trench MOSFET 25 March 2015

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006-3 (SOT883) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Very fast switching
- ElectroStatic Discharge (ESD) protection > 2 kV HBM
- Leadless ultra small SMD plastic package: 1.0 x 0.6 x 0.48 mm

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quid	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C	[1]	-	-	590	mA
Static characte	Static characteristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I _D = 590 mA; T _j = 25 °C		-	550	670	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	1	D
2	S	source	2 2 3	
3	D	drain	Transparent top view DFN1006-3 (SOT883)	G S 017aaa255

6. Ordering information

Table 3. Ordering int	formation		
Type number	Package		
	Name	Description	Version
PMZ550UNE	DFN1006-3	DFN1006-3: leadless ultra small plastic package; 3 solder lands	SOT883

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMZ550UNE	ZK

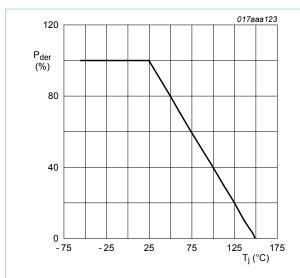
8. Limiting values

Table 5.Limiting values

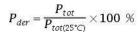
In accordance with the Absolute Maximum Rating System (IEC 60134).

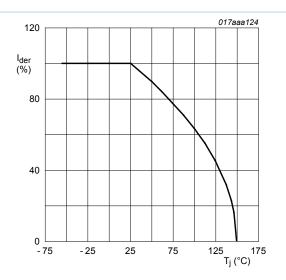
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	590	mA
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	370	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	2.3	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	310	mW
			[1]	-	400	mW
		T _{sp} = 25 °C		-	1670	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	380	mA

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.











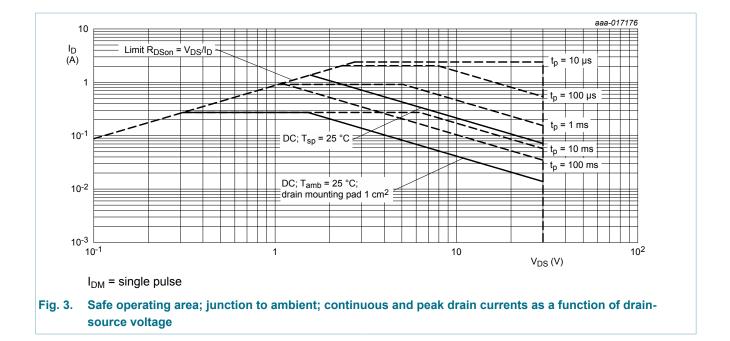
$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

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9. Thermal characteristics

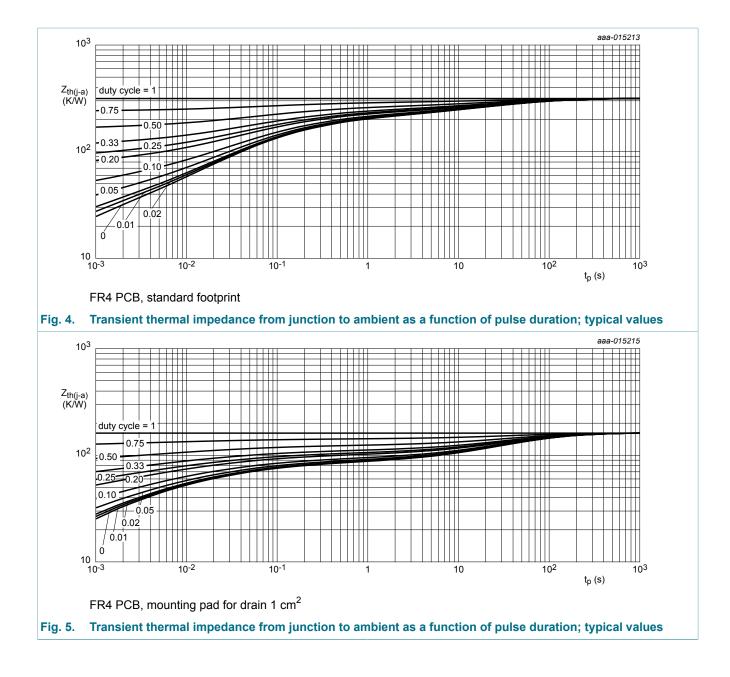
Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1]	-	350	405	K/W
	from junction to ambient		[2]	-	270	310	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	65	75	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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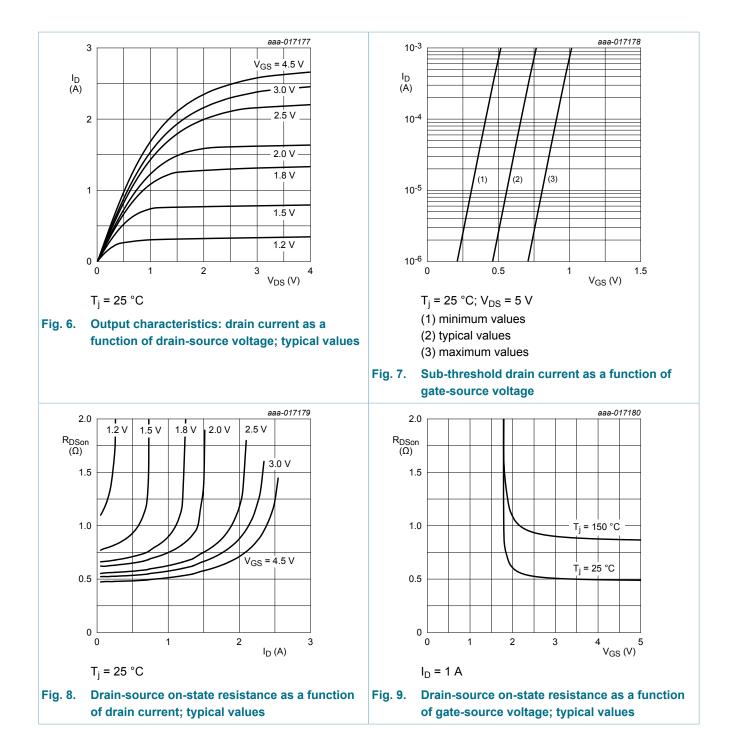


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	30	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} = V _{GS} ; T _j = 25 °C	0.45	0.7	0.95	V
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	5	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-5	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V_{GS} = 2.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
		V_{GS} = -2.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
R _{DSon}	drain-source on-state	V_{GS} = 4.5 V; I _D = 590 mA; T _j = 25 °C	-	550	670	mΩ
resistance	resistance	V _{GS} = 4.5 V; I _D = 590 mA; T _j = 150 °C	-	960	1170	mΩ
		V_{GS} = 2.5 V; I _D = 590 mA; T _j = 25 °C	-	660	900	mΩ
		V _{GS} = 1.8 V; I _D = 80 mA; T _j = 25 °C	-	770	1120	mΩ
		V_{GS} = 1.5 V; I _D = 10 mA; T _j = 25 °C	-	890	1500	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 590 mA; T _j = 25 °C	-	600	-	mS
Dynamic ch	aracteristics	· · · · · ·				
Q _{G(tot)}	total gate charge	V_{DS} = 15 V; I _D = 590 mA; V _{GS} = 4.5 V;	-	0.6	1.1	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.1	-	nC
Q _{GD}	gate-drain charge		-	0.1	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V;	-	30.3	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	5.8	-	pF
C _{rss}	reverse transfer capacitance		-	4.2	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; I _D = 590 mA; V _{GS} = 4.5 V;	-	4	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	7	-	ns
t _{d(off)}	turn-off delay time	1	-	12	-	ns
t _f	fall time		-	3	-	ns
Source-drai	in diode	· · · · · · · · · · · · · · · · · · ·	1	- 1		
V _{SD}	source-drain voltage	I _S = 380 mA; V _{GS} = 0 V; T _i = 25 °C	-	0.86	1.2	V

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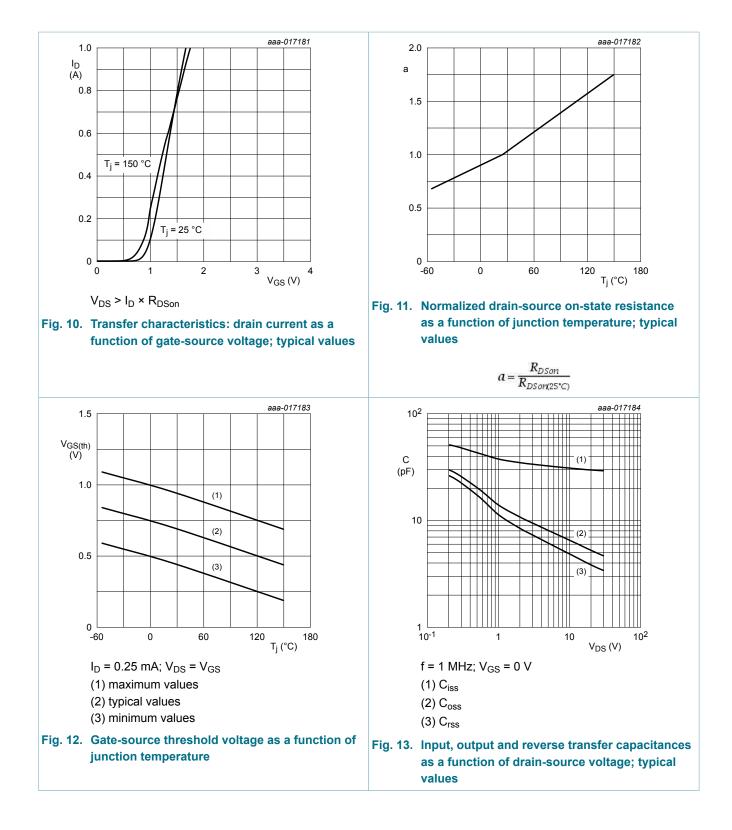
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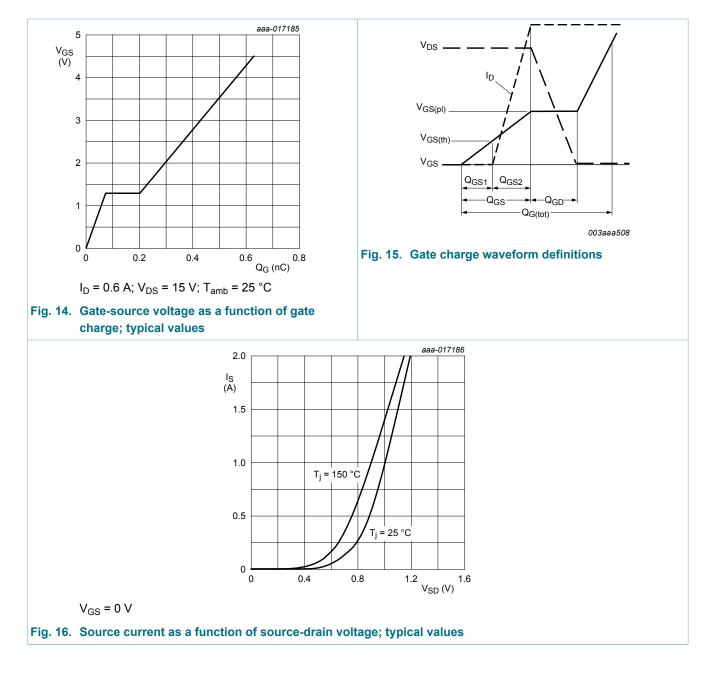
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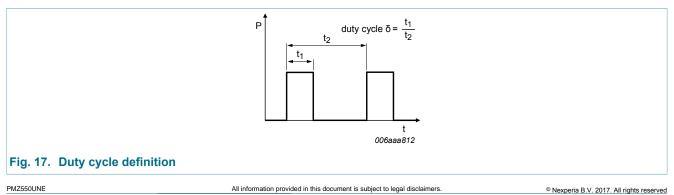
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11. Test information



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12. Package outline

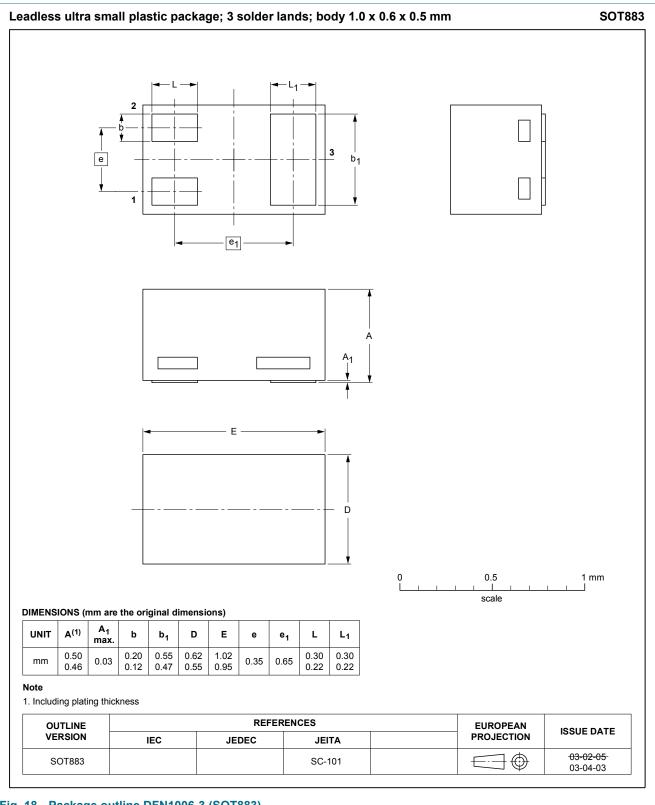
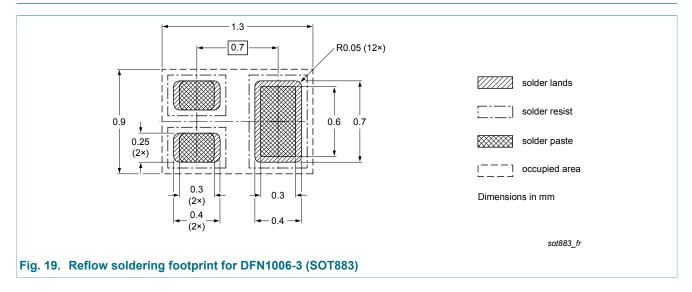


Fig. 18. Package outline DFN1006-3 (SOT883)
PMZ550UNE All information

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13. Soldering



14. Revision history

Table 8. Revision his	e 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMZ550UNE v.1	20150325	Product data sheet	-	-		

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15. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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